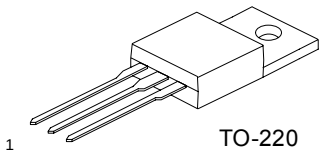
YAREN TECHNOLOGY

MBR2035/ 45/ 50/ 60CT

20A SCHOTTKY BARRIER DIODE
Dual High Voltage Schottky Rectifier

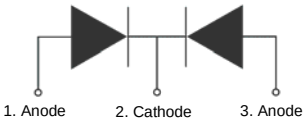
Specification Features:

- High Voltage Wide Range Selection, 35V, 45V,50V &60V
- High Switching Speed Device
- Low Forward Voltage Drop
- Low Power Loss and High Efficiency
- Guard Ring for Over-voltage Protection
- High Surge Capability
- RoHS Compliant
- Matte Tin(Sn) Lead Finish
- Terminal Leads Surface is Corrosion Resistant and can withstand to 260°C Wave Soldering or per MIL-STD-750, Method 2026.



TO-220

TO-220AB



POLARITY CONFIGURATION

DEVICE MARKING DESIGNATION:
Line 1 & 2= Device Name
Line 3 = Datecode
Line 4 = Polarity

Schottky Rectifiers

Absolute Maximum Ratings* T_A = 25°C unless otherwise noted

Symbol	Parameter	Value				Units
		2035CT	2045CT	2050CT	2060CT	
V_{RRM}	Maximum Repetitive Reverse Voltage	35	45	50	60	V
$I_{F(AV)}$	Average Rectified Forward Current .375 " lead length @ T_A = 135°C	20				A
I_{FSM}	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	150				A
T_{stg}	Storage Temperature Range	-65 to +175				°C
T_J	Operating Junction Temperature	-65 to +150				°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P_D	Power Dissipation	2.0	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient *	60	°C/W
$R_{\theta JL}$	Thermal Resistance, Junction to Lead	2.0	°C/W

Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Device				Units
		2035CT	2045CT	2050CT	2060CT	
V_F	Forward Voltage I_F = 10 A, T_C = 25°C	-		0.80		V
	I_F = 10 A, T_C = 125°C	0.57		0.70		V
	I_F = 20 A, T_C = 25°C	0.84		0.95		V
	I_F = 20 A, T_C = 125°C	0.72		0.85		V
I_R	Reverse Current @ rated V_R T_A = 25°C	0.1		0.15		mA
	T_A = 125°C	15		150		mA
I_{RRM}	Peak Repetitive Reverse Surge Current 2.0 us Pulse Width, f = 1.0 KHz	1.0		0.5		A